NSN 5962-01-065-9893

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-065-9893
Body Length:
Between 0.755 inches and 0.790 inches
Body Width:
Between 0.265 inches and 0.300 inches
Body Height:
Between 0.155 inches and 0.175 inches
Maximum Power Dissipation Rating:
650.0 milliwatts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set type an/fps-115
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and w/open collector and
bipolar and w/enable and w/decoded output
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
04761-640-200061 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:

Demilitarization:

Unit Of Measure:

N/a

NSN 5962-01-065-9893

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0